INTEGRATED CIRCUITS



Product specification Supercedes data of 1997 Nov 07 IC24 Data Handbook 1998 Jul 29



Philips Semiconductors

74LVC157A

FEATURES

- Wide supply voltage range of 1.2 to 3.6 V
- In accordance with JEDEC standard no. 8-1A
- CMOS lower power consumption
- Direct interface with TTL levels
- 5 Volt tolerant inputs, for interfacing with 5 Volt logic

DESCRIPTION

The 74LVC157A is a high-performance, low-power, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3V or 5.0V devices. In 3-State operation, outputs can handle 5V. This feature allows the use of these devices as translators in a mixed 3.3V/5V environment.

The 74LVC157A is a quad 2-input multiplexer which select 4 bits of data from two sources under the control of a common data select

input (S). The four outputs present the selected data in the true (non-inverted) form. The enable input (E) is active LOW. When E is HIGH, all of the outputs (1Y to 4Y) are forced LOW regardless of all other input conditions. Moving the data from two groups of registers to four common output buses is a common use of the 74LV157. The state of the common data select input (S) determines the particular register from which the data comes. It can also be used as function generator.

The device is useful for implementing highly irregular logic by generating any four of the 16 different functions of two variables with one variable common.

The 74LVC157A is the logic implementation of a 4-pole, 2-position switch, where the position of the switch is determined by the logic levels applied to S.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5$ ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay nl ₀ , nl1, to nY E to nY S to nY	C _L = 50 pF; V _{CC} = 3.3 V	3.1 3.0 3.3	ns
Cl	Input capacitance		5.0	pF
C _{PD}	Power dissipation capacitance per gate	$V_{I} = GND$ to V_{CC}^{1}	33	pF

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W)

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz; C_L = output load capacitance in pF;

 $f_o = \text{output frequency in MHz; } V_{CC} = \text{supply voltage in V; } \Sigma (C_L \times V_{CC}^2 \times f_o) = \text{sum of the outputs.}$

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
16-Pin Plastic SO	-40°C to +85°C	74LVC157A D	74LVC157A D	SOT109-1
16-Pin Plastic SSOP Type II	-40°C to +85°C	74LVC157A DB	74LVC157A DB	SOT338-1
16-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVC157A PW	74LVC157APW DH	SOT403-1

PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION	
1	S	Common data select input	
2, 5, 11, 14	$1I_0$ to $4I_0$	Data inputs from sources 0	
3, 6, 10, 13	1l ₁ to 4l ₁	Data inputs from sources 1	
4, 7, 9, 12	1Y to 4Y	Multiplexer outputs	
8	GND	Ground (0 V)	
15	Ē	Enable input (active LOW)	
16	V _{CC}	Positive supply voltage	

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LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTIONAL DIAGRAM



FUNCTION TABLE

	OUTPUTS			
Ē	S	nl ₀	nl ₁	nY
Н	Х	Х	Х	L
L	L	L	Х	L
L	L	н	Х	н
L	н	Х	L	L
L	Н	Х	Н	Н

NOTES:

H = HIGH voltage level L = LOW voltage level

X = don't care

LOGIC DIAGRAM



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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT		
STINBUL	PARAMETER	CONDITIONS	MIN	MAX	UNIT	
N	DC supply voltage (for max. speed performance)		2.7	3.6	V	
V _{CC}	DC supply voltage (for low-voltage applications)		1.2	3.6	V	
VI	DC input voltage range		0	5.5	V	
Vo	DC output voltage range		0	V _{CC}	V	
T _{amb}	Operating free-air temperature range		-40	+85	°C	
t _r , t _f	Input rise and fall times	V _{CC} = 1.2 to 2.7V V _{CC} = 2.7 to 3.6V	0 0	20 10	ns/V	

ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +6.5	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
VI	DC input voltage	Note 2	-0.5 to +5.5	V
I _{OK}	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	± 50	mA
V _O	DC output voltage	Note 2	–0.5 to V _{CC} +0.5	V
Ι _Ο	DC output diode current	$V_{O} = 0$ to V_{CC}	± 50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

			L	UNIT				
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -					
			MIN	TYP ¹	МАХ			
M		V _{CC} = 1.2V	V _{CC}			v		
V _{IH}	HIGH level Input voltage	V _{CC} = 2.7 to 3.6V	2.0					
V		$V_{CC} = 1.2V$			GND			
V _{IL}	LOW level Input voltage	V _{CC} = 2.7 to 3.6V			0.8			
		V_{CC} = 2.7V; V_{I} = V_{IH} or V_{IL} ; I_{O} = -12mA	V _{CC} -0.5					
		V_{CC} = 3.0V; V_I = V_{IH} or V_{IL} ; I_O = -100 μ A	V _{CC} -0.2	V _{CC}		V		
V _{OH}	HIGH level output voltage	$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -18mA$	V _{CC} -0.6					
		V_{CC} = 3.0V; V_{I} = V_{IH} or V_{IL} ; I_{O} = -24mA	V _{CC} -0.8					
		V_{CC} = 2.7V; V_I = V_{IH} or V_{IL} ; I_O = 12mA			0.40			
V _{OL}	LOW level output voltage	V_{CC} = 3.0V; $V_I = V_{IH}$ or V_{IL} ; I_O = 100 μ A		GND	0.20	V		
		V_{CC} = 3.0V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 24mA			0.55			
t _l	Input leakage current	V_{CC} = 3.6V; V_{I} = 5.5V or GND		±0.1	±5	μA		
I _{CC}	Quiescent supply current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or } \text{GND}; I_O = 0$		0.1	10	μΑ		
ΔI_{CC}	Additional quiescent supply current per input pin	V_{CC} = 2.7V to 3.6V; V_{I} = V_{CC} –0.6V; I_{O} = 0		5	500	μA		

NOTE:

1. All typical values are measured at V_{CC} = 3.3V and T_{amb} = 25°C.

AC CHARACTERISTICS

GND = 0 V; t_{r} = t_{f} $\leq\,$ 2.5 ns; C_{L} = 50 pF; R_{L} = 500\Omega; T_{amb} = –40°C to +85°C

			LIMITS						
SYMBOL	PARAMETER	WAVEFORM	Vcc	; = 3.3V ±0).3V	V _{CC} =	2.7V	V _{CC} = 1.2V	UNIT
			MIN	TYP ¹	MAX	MIN	MAX	TYP	
t _{PHL} /t _{PLH}	Propagation delay nl ₀ to nY; nl ₁ to nY	Figure 2, 3	1.5	3.1	5.7	1.5	6.7	12	ns
t _{PHL} /t _{PLH}	Propagation delay E to nY	Figure 1, 3	1.5	3.0	6.3	1.5	7.3	11	ns
t _{PHL} /t _{PLH}	Propagation delay S to nY	Figure 2, 3	1.5	3.3	6.8	1.5	7.8	13	ns

NOTE:

1. These typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

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AC WAVEFORMS

 $\begin{array}{l} V_{M} = 0.5 \times V_{CC} \mbox{ at } V_{CC} < 2.7 \ V \\ V_{M} = 1.5 \ V \mbox{ at } V_{CC} \geq 2.7 \ V \\ V_{X} = V_{OL} + 0.3 \ V \mbox{ at } V_{CC} \geq 2.7 \ V \\ V_{X} = V_{OL} + 0.1 \times V_{CC} \mbox{ at } V_{CC} < 2.7 \ V \\ V_{Y} = V_{OH} - 0.3 \ V \mbox{ at } V_{CC} \geq 2.7V \\ V_{Y} = V_{OH} - 0.1 \times V_{CC} \mbox{ at } V_{CC} < 2.7 \ V \\ V_{OL} \mbox{ and } V_{OH} \mbox{ are the typical output voltage drop that occur with the output load.} \end{array}$



Figure 1. Enable input (E) to output (nY) propagation delays.



Figure 2. Data inputs (nI_0, nI_1) and common data select input (S) to output (nY) propagation delays.

TEST CIRCUIT



Figure 3. Load circuitry for switching times.

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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